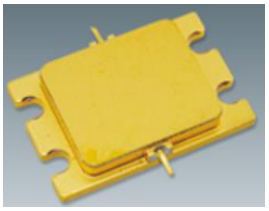
2.7-3.5GHz, 28V 200W, GaN Fully matched PA Module



Description

The GMAH2735-200H2 is a 200-watt,single stage integrated Power Amplifier Module, designed for broad band applications, with frequencies from 2.7 to 3.5GHz.

The module is 50 Ω input/output matched and requires minimal external components.

The module implements multiple GaN active dice and its matching network within highly compact 24*17mm metal RF package with excellent capability for heat dissipation.

It is recommended to use it only for pulsed application

V_{DS}= 28V, I_{DQ}=350mA(Vgs=-2.7V), 20us,10%

Freq (MHz)	P1dB Gain(dB)	Psat (dBm)	Psat (W)	Psat Eff(%)
2700	13.04	53.92	246.4	66.2
2800	15.28	53.46	221.9	63.6
2900	16.05	53.43	220.5	60.3
3000	15.91	53.74	236.5	59.0
3100	15.57	53.75	237.2	56.5
3200	15.94	53.82	241.2	55.1
3300	15.76	53.9	245.6	55.1
3400	15.52	53.8	239.6	56.3
3500	13.91	53.42	220.0	58.4

Product Features

- Operating Frequency Range: 2.7-3.5GHz
- Operating Drain Voltage(Recommended): +28V (32V with increased power capability)
- 50 Ω Input/Output (External DC block capacitor needed)
- Psat⩾200W (Pulse)
- Small signal gain:>14dB, Power gain:>11dB @200W
- Minimum Psat efficiency:>55%
- 24*17 mm metal RF package
- Compliant to Restriction of Hazardous Substances (RoHS) Directive 2002/95/EC

Applications

- S band pulsed amplifier

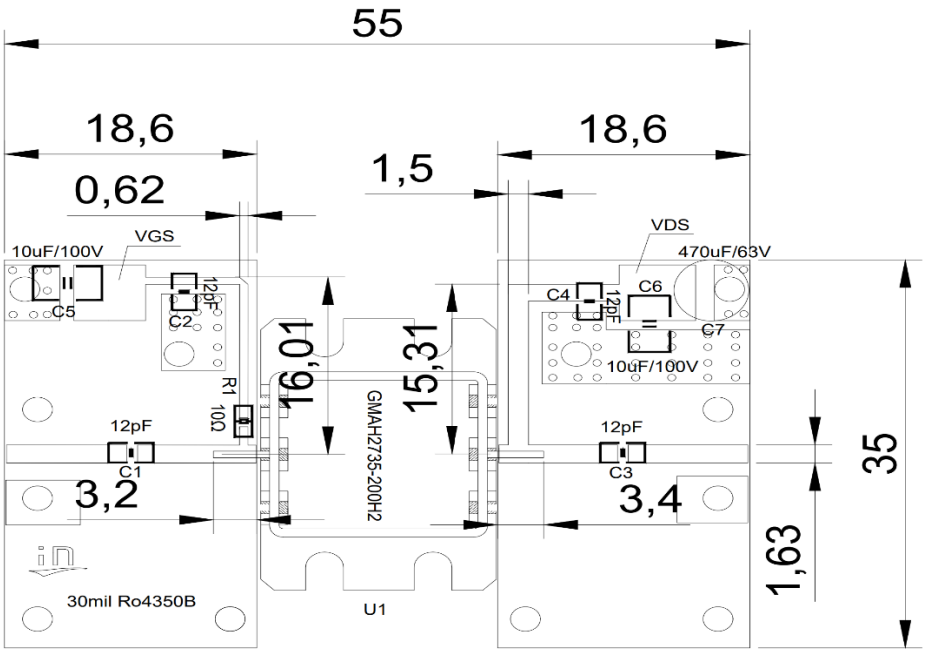
Table 1. Maximum Ratings

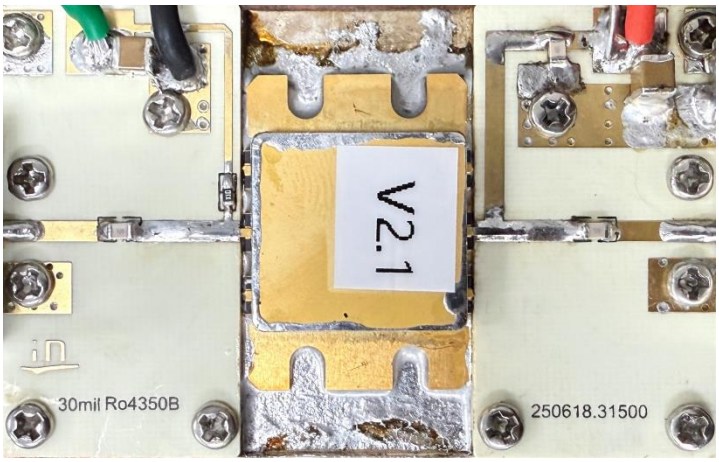
Rating	Symbol	Value	Unit
Drain--Source Voltage	V_{DSS}	150	Vdc
Gate--Source Voltage	V_{GS}	-10 to +2	Vdc
Operating Voltage	V_{DD}	+36	Vdc
Storage Temperature Range	Tstg	-65 to +150	°C
Case Operating Temperature	T_C	+150	°C
Operating Junction Temperature	T_J	+225	°C

Table 2. Thermal Characteristics

Characteristic	Symbol	Value	Unit
Thermal Resistance, Junction to Case T_C= 25°C, Pout=300W, FEA	$R_{\theta JC}$	TBD	°C/W

Typical application circuit





Reference	Footprint	Value	Quantity
C1, C2, C3, C4	0805	12pF/250V	4
C5, C6	1210	10uF/100V	2
C7		470 uF/63V	1
R1	0603	10R	1
U1	H2	GMAH2735-200H2$^{V2.1}$	1

TYPICAL CHARACTERISTICS

Figure 1. Network analyzer output S11/S21 (Pin=0dBm), Vds=28V, Idq=600mA

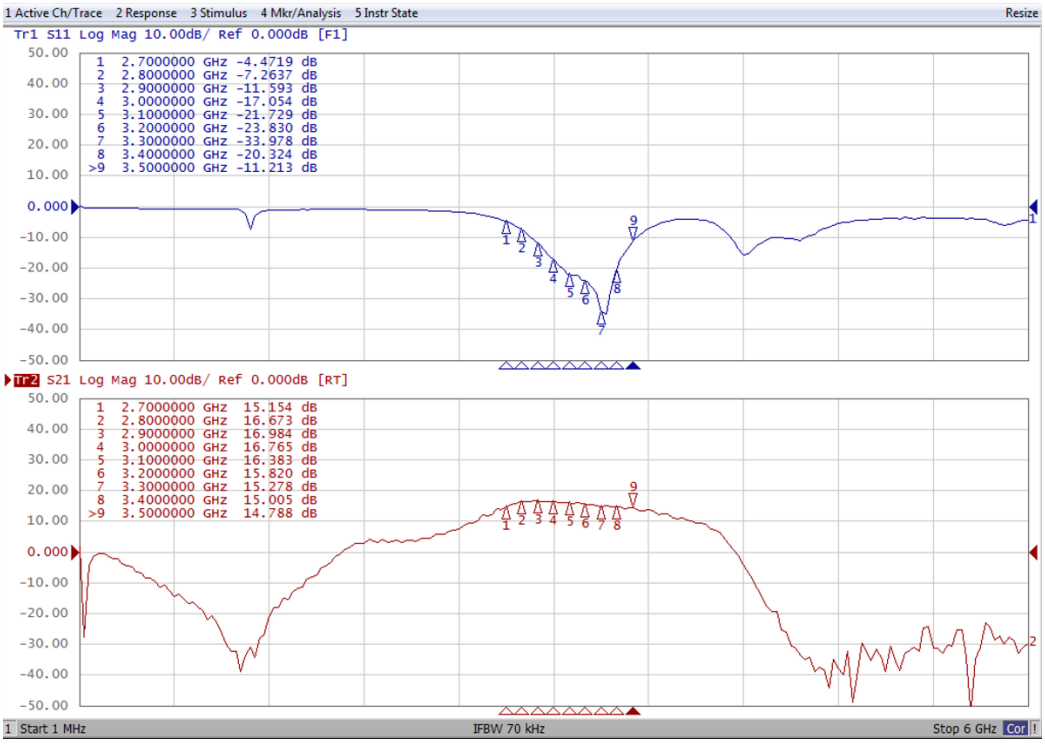
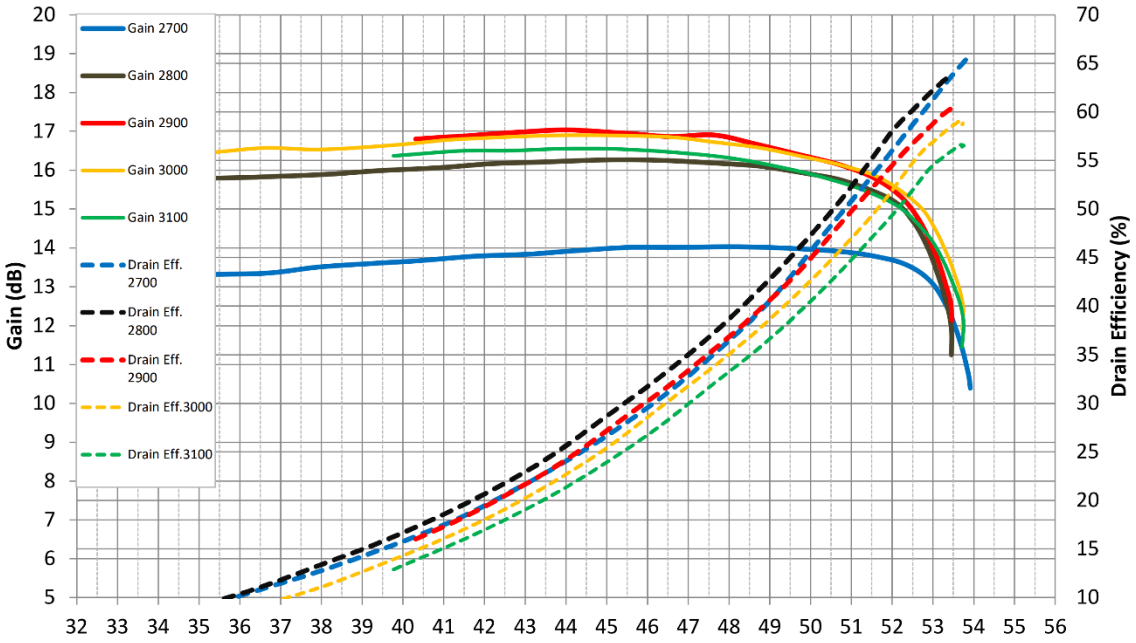


Figure 2. Power Gain, Efficiency as function of Pout at 28V



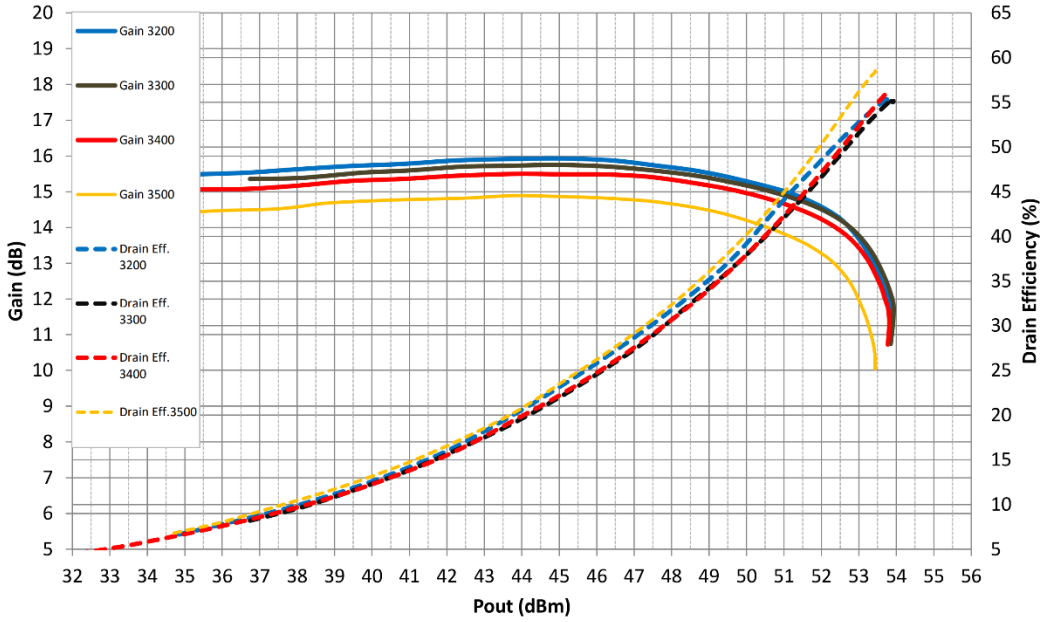
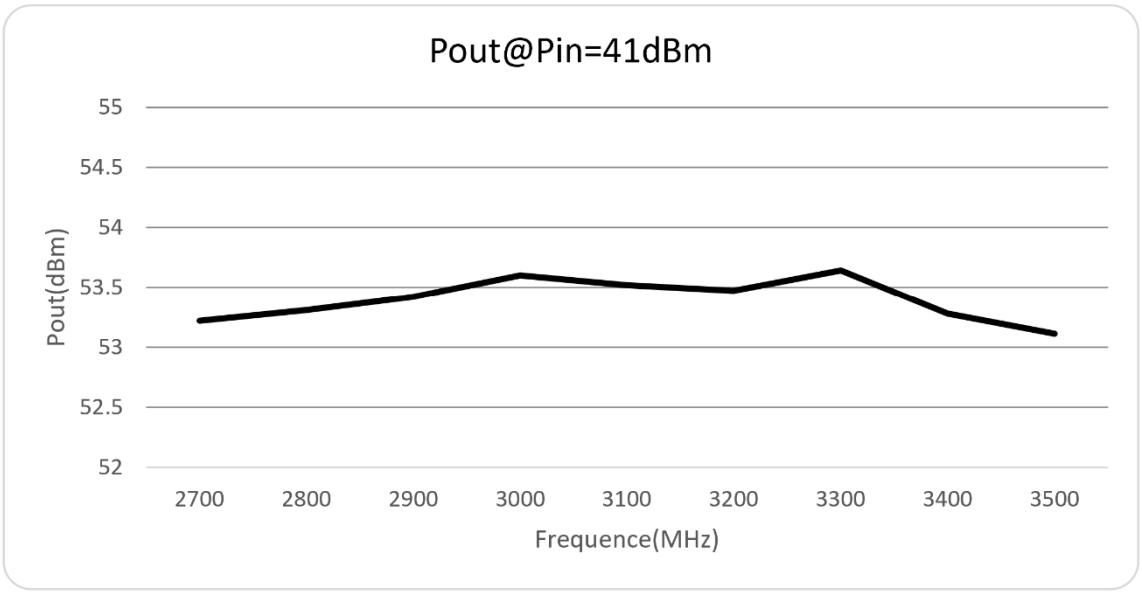
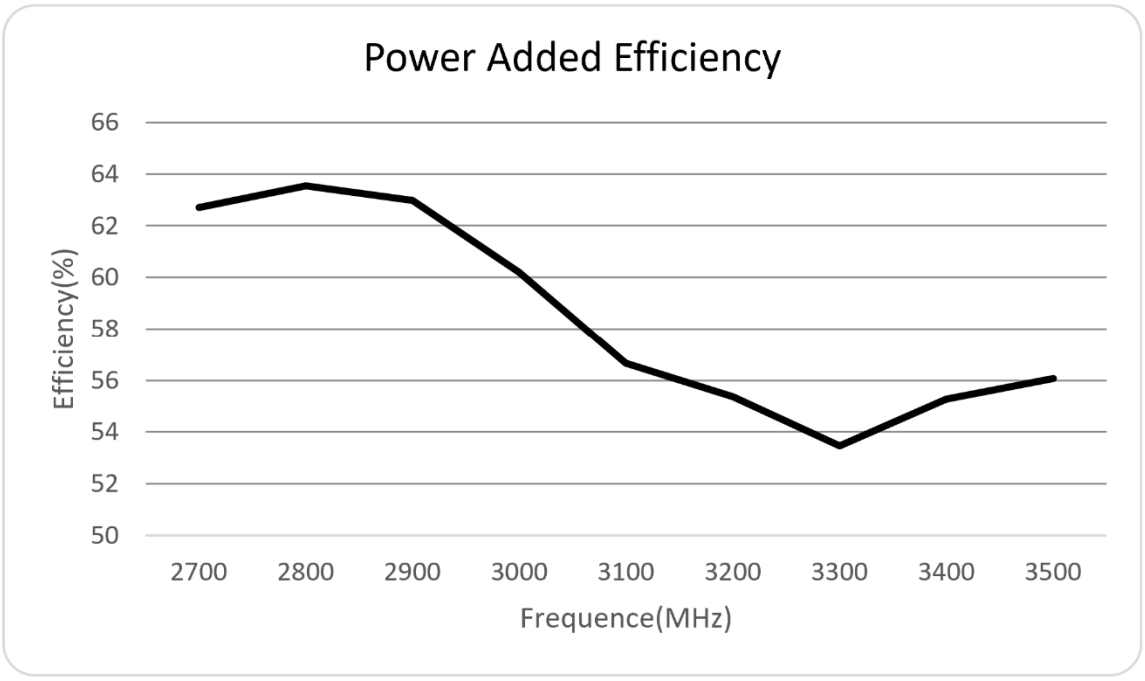


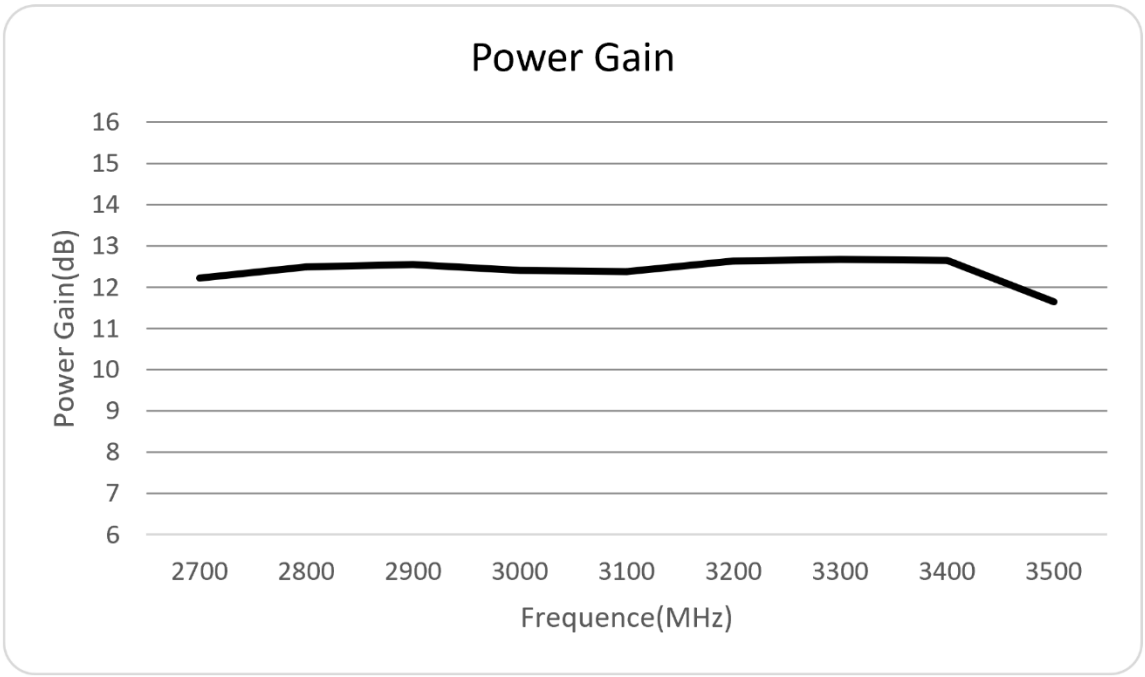
Figure 3. Pout and Efficiency ,Power gain at fixed input 41dBm



Pout vs Frequency

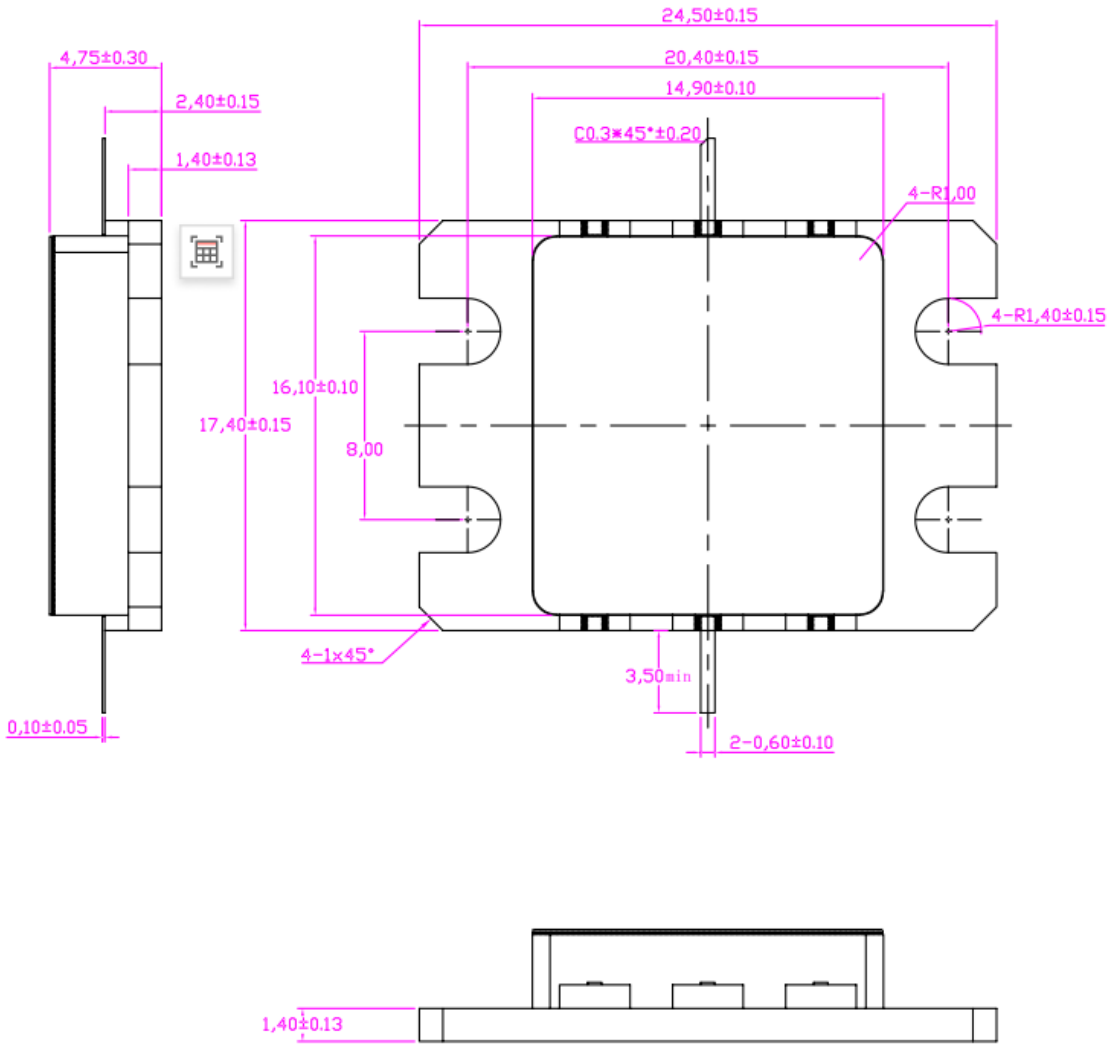


Efficiency vs Frequency



Efficiency vs Power Gain

Package Dimensions （Unit:mm）



Revision history

Table 6. Document revision history

Date	Revision	Datasheet Status
2026/6/1	Rev 1.0	Preliminary datasheet

Application data based on ZBB-26-09

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